

SOT-23 Formed SMD Package

BCX19
BCX20

SILICON PLANAR EPITAXIAL TRANSISTORS

N-P-N transistors

Marking

BCX19 = U1

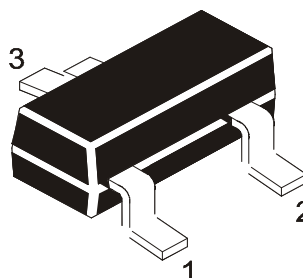
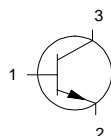
BCX20 = U2

Pin configuration

1 = BASE

2 = EMITTER

3 = COLLECTOR



ABSOLUTE MAXIMUM RATINGS

		BCX19	BCX20
Collector-emitter voltage ($V_{BE} = 0$)	V_{CES} max.	50	30 V
Collector-emitter voltage (open base)	V_{CE0} max.	45	25 V
Collector current (peak value)	I_{CM} max.	1000	mA
Total power dissipation up to $T_{amb} = 25\text{ }^{\circ}\text{C}$	P_{tot} max.	250	mW
Junction temperature	T_j max.	150	$^{\circ}\text{C}$
D.C. current gain	h_{FE}	100 to 600	
Transition frequency	f_T typ.	200	MHz
$I_C = 10\text{ mA}; V_{CE} = 5\text{ V}; f = 35\text{ MHz}$			

BCX19 BCX20

RATINGS (at $T_A = 25^\circ\text{C}$ unless otherwise specified)

Limiting values

		BCX19	BCX20
Collector-emitter voltage ($V_{BE} = 0$)	V_{CES} max.	50	30 V
Collector-emitter voltage (open base)			
$I_C = 10\text{ mA}$	V_{CE0} max.	45	25 V
Emitter-base voltage (open collector)	V_{EB0} max.	5	5 V
Collector current (d.c.)	I_C max.	500	mA
Collector current (peak value)	I_{CM} max.	1000	mA
Emitter current (peak value)	$-I_{EM}$ max.	1000	
Base current (d.c.)	I_B max.	100	mA
Base current (peak value)	I_{BM} max.	200	mA
Total power dissipation up to $T_{amb} = 25^\circ\text{C}^*$	P_{tot} max.	250	mW
Storage temperature	T_{stg}	-55 to +150	$^\circ\text{C}$
Junction temperature	T_j max.	150	$^\circ\text{C}$

THERMAL RESISTANCE

$$R_{th\ j-a} = 500\text{ KW}$$

From junction to ambient

CHARACTERISTICS

$T_j = 25^\circ\text{C}$ unless otherwise specified

Collector cut-off current

$$I_E = 0; V_{CB} = 20\text{ V}$$

$$I_{CB0} < 100\text{ nA}$$

$$I_E = 0; V_{CB} = 20\text{V}; T_j = 150^\circ\text{C}$$

$$I_{CB0} < 5\text{ }\mu\text{A}$$

Emitter cut-off current

$$I_C = 0; V_{EB} = 5\text{ V}$$

$$I_{EB0} < 10\text{ }\mu\text{A}$$

Base emitter voltage

$$I_C = 500\text{ mA}; V_{CE} = 1\text{ V}$$

$$V_{BE} < 1,2\text{ V}$$

Saturation voltage

$$I_C = 500\text{ mA}; I_B = 50\text{ mA}$$

$$V_{CEsat} < 620\text{ mV}$$

D.C. current gain

$$I_C = 100\text{ mA}; V_{CE} = 1\text{ V}$$

$$h_{FE} 100\text{ to }600$$

$$I_C = 300\text{ mA}; V_{CE} = 1\text{ V}$$

$$h_{FE} > 70$$

$$I_C = 500\text{ mA}; V_{CE} = 1\text{ V}$$

$$h_{FE} > 40$$

Transition frequency at $f = 35\text{ MHz}$

$$I_C = 10\text{ mA}; V_{CE} = 5\text{ V}$$

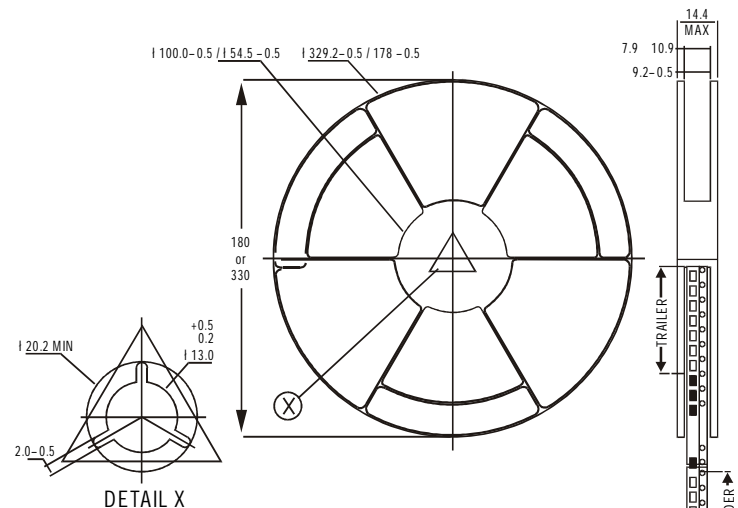
$$f_T \text{ typ. } 200\text{ MHz}$$

Collector capacitance at $f = 1\text{ MHz}$

$$I_E = I_e = 0; -V_{CB} = 10\text{ V}$$

$$C_c \text{ typ. } 5\text{ pF}$$

SOT-23 Package Reel Information
Reel specifications for Packing (13"/7" reels)



NOTES:

	8mm Tape	8mm Tape
	Size of Reel	Size of Reel
	330 mm (13")	180 mm (7")
No. of Devices	10,000 Pcs	3,000 Pcs

1. The bandolier of 330 mm reel contains at least 10,000 devices.
2. The bandolier of 180 mm reel contains at least 3,000 devices.
3. No more than 0.5% missing devices / reel. 50 empty compartments for 330 mm reel. 15 empty compartments for 180 mm reel.
4. Three consecutive empty places might be found provided this gap is followed by 6 consecutive devices.
5. The carrier tape (leader) starts with at least 75 empty positions (equivalent to 330 mm). In order to fix the carrier tape a self adhesive tape of 20 to 50 mm is applied. At the end of the bandolier at least 40 empty positions (equivalent to 160 mm) are there.

Technical drawing of a wire mesh strip, showing a cross-section and a plan view with dimensions in mm.

Cross-section (Left):

- Overall width: 1.6 MAX
- Wire diameter: 1.22
- Mesh opening width: 0.1
- Mesh opening height: 2.77
- Mesh opening depth: -0.10

Plan View (Right):

- Overall width: 8.0
- Wire diameter: 1.22
- Mesh opening width: 0.1
- Mesh opening height: 2.77
- Mesh opening depth: -0.10
- Mesh opening width: 1.75
- Mesh opening height: 3.5
- Mesh opening depth: -0.05
- Mesh opening width: 5.75 MAX
- Mesh opening height: 8.0
- Mesh opening depth: -0.1
- Mesh opening width: 4.0
- Mesh opening height: 4.0
- Mesh opening depth: -0.05
- Mesh opening width: 1.55
- Mesh opening height: 1.0
- Mesh opening depth: -0.05
- Mesh opening width: 3.15
- Mesh opening height: -0.10

Direction of Unreeling

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Packing Detail

PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX		
	Details	Net Weight/Qty	Size	Qty	Size	Qty	Gr Wt
SOT-23 T&R	3K/reel	136 gm/3K pcs	3" x 7.5" x 7.5"	12.0K	17" x 15" x 13.5"	192.0K	12 kgs
			9" x 9" x 9"	51.0K	19" x 19" x 19"	408.0K	28 kgs
	10K/reel	415 gm/10K pcs	13" x 13" x 0.5"	10.0K	17" x 15" x 13.5"	300.0K	16 kgs

Customer Notes

Component Disposal Instructions

1. CDIL Semiconductor Devices are RoHS compliant, customers are requested to please dispose as per prevailing Environmental Legislation of their Country.
2. In Europe, please dispose as per EU Directive 2002/96/EC on Waste Electrical and Electronic Equipment (WEEE).

Disclaimer

The product information and the selection guides facilitate selection of the CDIL's Discrete Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished on the CDIL Web Site/CD are believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Discrete Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

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